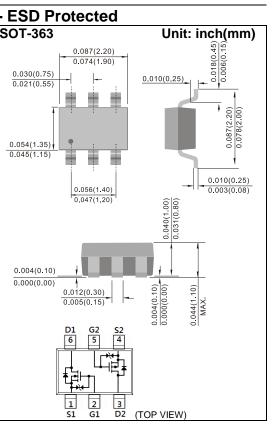


Features

- Low Voltage Drive (1.2V)
- Advanced Trench Process Technology
- Specially Designed for Switch Load, PWM Application, etc.
- ESD Protected
- Lead free in compliance with EU RoHS 2011/65/EU directive
- Green molding compound as per IEC61249 Std. (Halogen Free)

Mechanical Data

- Case: SOT-363 Package
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.0002 ounces, 0.006 grams



Maximum Ratings and Thermal Characteristics (T_A=25°C unless otherwise noted)

PARAMETE	SYMBOL	N-Ch LIMIT	P-Ch LIMIT	UNITS	
Drain-Source Voltage		V _{DS}	20 -20		V
Gate-Source Voltage		V _{GS}	<u>+</u> 10 <u>+</u> 10		V
Continuous Drain Current		ID	0.5	-0.5	А
Pulsed Drain Current (Note 4)		ldм	1.0	-1.0	А
	T₂=25°C		350		mW
Power Dissipation	Derate above 25°C	PD	2	mW/°C	
Operating Junction and Storage Te	TJ,TSTG	-55~150		°C	
Typical Thermal resistance - Junction to Ambient (Note 3)		Reja	357		°C/W



N-Channel Electrical Characteristics (T_A=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS	
Static							
Drain-Source Breakdown Voltage	BV _{DSS} V _{GS} =0V, I _D = 250uA		20	-	-	V	
Gate Threshold Voltage	$V_{GS(th)}$	V _{DS} =V _{GS} , I _D = 250uA	0.3	0.65	0.9	V	
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} = 4.5V, I _D = 500mA	4.5V, I _D = 500mA - 280		400		
		V _{GS} = 2.5V, I _D = 200mA	-	350	650		
		V _{GS} = 1.8V, I _D = 100mA	-	400	800	mΩ	
		V _{GS} = 1.5V, I _D = 50mA	-	500	1200	-	
		V _{GS} = 1.2V, I _D = 20mA	-	700	3000		
Zero Gate Voltage Drain Current	IDSS	V _{DS} =16V, V _{GS} =0V	-	-	1	uA	
Gate-Source Leakage Current	lgss	I _{GSS} V _{GS} = <u>+</u> 8V, V _{DS} =0V		<u>+</u> 0.5	<u>+</u> 10	uA	
Dynamic ^(Note 5)							
Total Gate Charge	Qg		-	1.4	-	nC	
Gate-Source Charge	Q _{gs}	V _{DS} =10V, I _D =500mA, V _{GS} =4.5V ^(Note 1,2)	-	0.22	-		
Gate-Drain Charge	Q_{gd}	VGS=4.5V (Note 1,2)	-	0.21	-		
Input Capacitance	Ciss		-	67	-	pF	
Output Capacitance	Coss	V _{DS} =10V, V _{GS} =0V,	-	19	-		
Reverse Transfer Capacitance	Crss	f=1.0MHZ	-	6	-		
Switching							
Turn-On Delay Time	td _(on)		-	2.8	-		
Turn-On Rise Time	tr	$V_{DD}=10V, I_{D}=150mA,$	-	20	-		
Turn-Off Delay Time	td _(off)	V _{GS} =4.0V, R _G =10Ω	-	23	-	ns	
Turn-Off Fall Time	tf		-	23	-		
Drain-Source Diode							
Maximum Continuous Drain-Source	Is		-	-	500	mA	
Diode Forward Current Diode Forward Voltage	V _{SD}	Is= 500mA, V _{GS} =0V	-	0.87	1.3	V	



P-Channel Electrical Characteristics (T_A=25°C unless otherwise noted)

PARAMETER	SYMBOL TEST CONDITION		MIN.	TYP.	MAX.	UNITS	
Static		·					
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D = -250uA	-20	-	-	V	
Gate Threshold Voltage	V _{GS(th)} V _{DS} =V _{GS} , I _D = -250uA		-0.3	-0.6	-1	V	
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} = -4.5V, I _D =-500mA - 85		850	1200		
		V _{GS} = -2.5V, I _D =-200mA	-	990	1500		
		V _{GS} = -1.8V, I _D =-100mA	-	1160	2200	mΩ	
		V _{GS} = -1.5V, I _D = -50mA	-	1330	3600		
		V _{GS} = -1.2V, I _D = -10mA	-	1500	6000		
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =-16V, V _{GS} =0V	-	-	-1	uA	
Gate-Source Leakage Current	Igss	ss V _{GS} = <u>+</u> 8V, V _{DS} =0V		<u>+</u> 2	<u>+</u> 10	uA	
Dynamic ^(Note 5)							
Total Gate Charge	Qg		-	1.4	-	nC	
Gate-Source Charge	Q _{gs}	V _{DS} =-10V, I _D =-500mA, V _{GS} =-4.5V ^(Note 1,2)	-	0.19	-		
Gate-Drain Charge	Q_{gd}	VGS=-4.5V (Note 1,2)	-	0.2	-		
Input Capacitance	Ciss		-	38	-	pF	
Output Capacitance	Coss	V_{DS} =-10V, V_{GS} =0V,	-	15	-		
Reverse Transfer Capacitance	Crss	f=1.0MHZ	-	9	-		
Switching							
Turn-On Delay Time	td _(on)		-	7.2	-	ns	
Turn-On Rise Time	tr	V_{DD} =-10V, I_{D} =-500mA,	-	21	-		
Turn-Off Delay Time	td _(off)	V _{GS} =-4.5V, R _G =6Ω	-	85	-		
Turn-Off Fall Time	tf		-	116	-		
Drain-Source Diode							
Maximum Continuous Drain-Source					500		
Diode Forward Current	I _S		-	-	-500	mA	
Diode Forward Voltage NOTES :	V _{SD}	Is=-500mA, V _{GS} =0V	-	-0.93	-1.3	V	

NOTES :

1. Pulse width

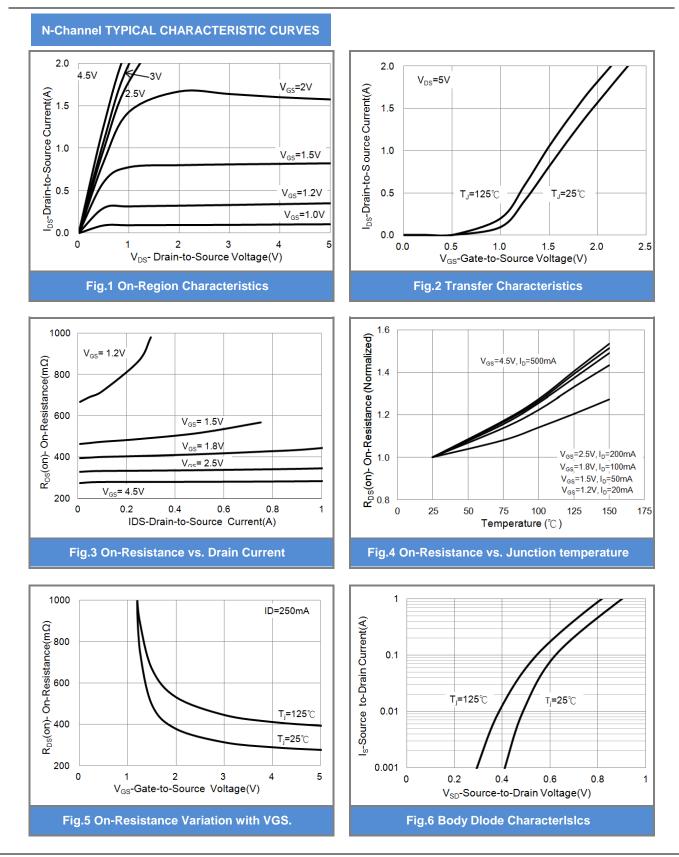
2. Essentially independent of operating temperature typical characteristics.

3. R_{OJA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper.

4. The maximum current rating is package limited.

5. Guaranteed by design, not subject to production testing.







N-Channel TYPICAL CHARACTERISTIC CURVES

Fig.7 Gate-Charge Characteristics

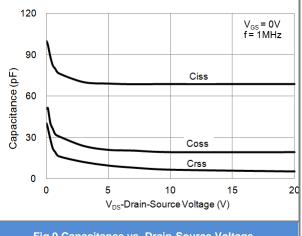
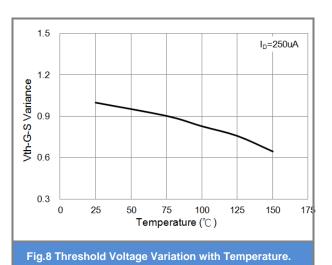
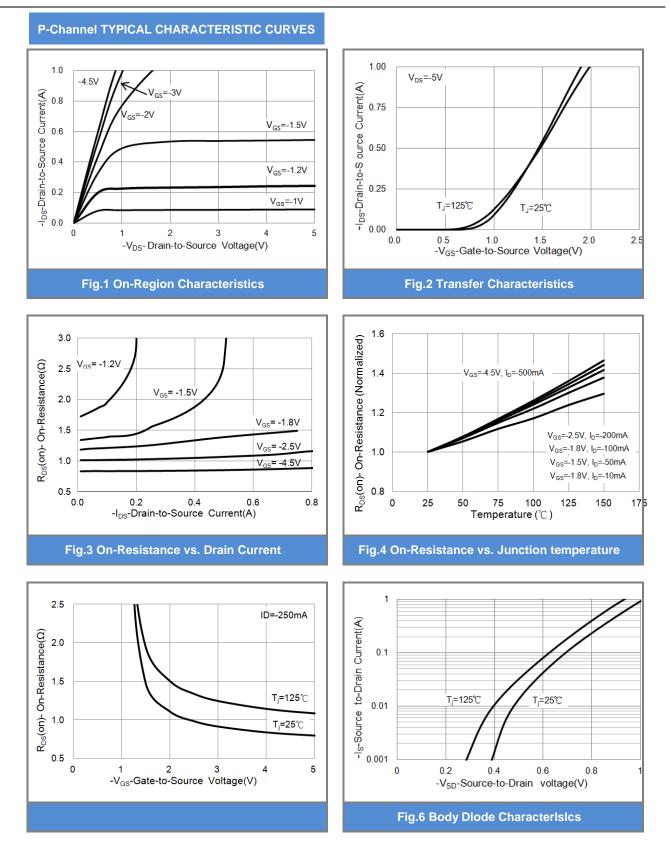


Fig.9 Capacitance vs. Drain-Source Voltage.









P-Channel TYPICAL CHARACTERISTIC CURVES

Fig.7 Gate-Charge Characteristics

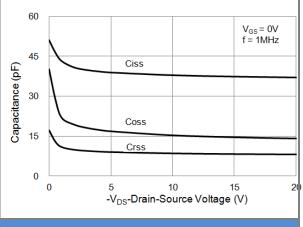
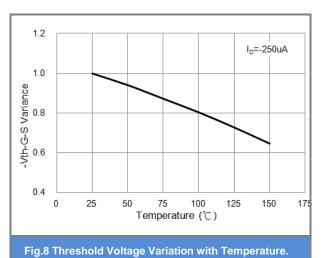


Fig.9 Threshold Voltage Variation with Temperature.

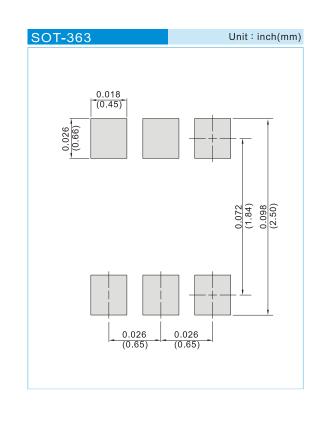




Product and Packing Information

Part No.	Package Type	Packing Type	Marking	
PJT7601	SOT-363	3K pcs / 7" reel	T61	
PJT7601	SOT-363	10K pcs / 13" reel	T61	

Mounting Pad Layout





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